

## ICS840002-32

# FEMTOCLOCKS<sup>TM</sup>CRYSTAL-TO-LVCMOS/LVTTL FREQUENCY SYNTHESIZER

### GENERAL DESCRIPTION



The ICS840002-32 is a 2 output LVCMOS/LVTTL Synthesizer optimized to generate Fibre Channel or Serial ATA reference clock frequencies and is a member of the HiPerClocks<sup>TM</sup> family of high performance

clock solutions from ICS. Using an 18pF parallel resonant crystal, the following frequencies can be generated based on 1 frequency select pin (SEL): 106.25MHz and 75MHz, or 212.5MHz. The ICS840002-32 uses ICS' 3<sup>rd</sup> generation low phase noise VCO technology and can achieve 1ps or lower typical rms phase jitter, easily meeting Fibre Channel and Serial ATA jitter requirements. The ICS840002-32 is packaged in a small 8-pin TSSOP package.

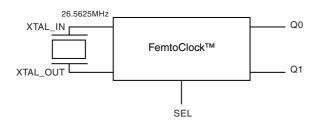
#### **F**EATURES

- Two LVCMOS/LVTTL outputs, 15Ω typical output impedance
- · Crystal oscillator interface
- Output frequency range: 75MHz and 106.25MHz, or 212.5MHz
- RMS phase jitter at 106.25MHZ (637kHz 5MHz): 0.86ps (typical)
- Full 3.3V or 3.3V core/2.5V output supply mode
- 0°C to 70°C ambient operating temperature

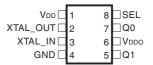
#### SELECT FUNCTION TABLE

Input	Output Frequency Range (MHz)				
SEL	Q0	Q1			
0	75	106.25			
1	75	212.5			

## **BLOCK DIAGRAM**



### PIN ASSIGNMENT



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**8-Lead TSSOP** 4.40mm x 3.0mm x 0.925mm package body

**G Package** Top View

The Preliminary Information presented herein represents a product in prototyping or pre-production. The noted characteristics are based on initial product characterization. Integrated Circuit Systems, Incorporated (ICS) reserves the right to change any circuitry or specifications without notice.



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#### TABLE 1. PIN DESCRIPTIONS

Number	Name	Ту	ре	Description
1	$V_{_{\mathrm{DD}}}$	Power		Core supply pin.
2, 3	XTAL_OUT, XTAL_IN	Input		Crystal oscillator interface.
4	GND	Power		Power supply ground.
5, 7	Q1, Q0	Output		Single-ended clock outputs. LVCMOS/LVTTL interface levels. $15\Omega$ typical output impedence.
1	V <sub>DDO</sub>	Power		Output supply pin.
8	SEL	Input	Pulldown	Select pin. LVCMOS/LVTTL interface levels.

NOTE: Pulldown refers to internal input resistors. See Table 2, Pin Characteristics, for typical values.

#### TABLE 2. PIN CHARACTERISTICS

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
C <sub>IN</sub>	Input Capacitance			4		рF
	Power Dissipation Capacitance	$V_{DD}, V_{DDO} = 3.465V$		TBD		рF
C <sub>PD</sub>		$V_{DD} = 3.465V, V_{DDO} = 2.625V$		TBD		pF
R <sub>PULLDOWN</sub>	Input Pulldown Resistor			51		kΩ
R <sub>out</sub>	Output Impedance			15		Ω



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#### ABSOLUTE MAXIMUM RATINGS

Supply Voltage, V<sub>nn</sub> 4.6V

Inputs,  $V_1$  -0.5V to  $V_{DD}$  + 0.5 V

Outputs,  $V_{\rm O}$  -0.5V to  $V_{\rm DDO}$  + 0.5V

Package Thermal Impedance, θ<sub>JA</sub> 101.7°C/W (0 mps)

Storage Temperature,  $T_{STG}$  -65°C to 150°C

NOTE: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the *DC Characteristics* or *AC Characteristics* is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

Table 3A. Power Supply DC Characteristics,  $V_{DD} = V_{DDO} = 3.3V \pm 5\%$ , Ta = 0°C to 70°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
$V_{_{ m DD}}$	Core Supply Voltage		3.135	3.3	3.465	V
V <sub>DDO</sub>	Output Supply Voltage		3.135	3.3	3.465	V
I <sub>DD</sub>	Power Supply Current			TBD		mA
I <sub>DDO</sub>	Output Supply Current			TBD		mA

Table 3B. Power Supply DC Characteristics,  $V_{DD} = 3.3V \pm 5\%$ ,  $V_{DDO} = 2.5V \pm 5\%$ , Ta = 0°C to 70°C to 7

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V <sub>DD</sub>	Core Supply Voltage		3.135	3.3	3.465	V
V <sub>DDO</sub>	Output Supply Voltage		2.375	2.5	2.625	V
I <sub>DD</sub>	Power Supply Current			TBD		mA
I <sub>DDO</sub>	Output Supply Current			TBD		mA

#### Table 3C. LVCMOS/LVTTL DC Characteristics, $V_{DD} = 3.3V \pm 5\%$ , $V_{DDO} = 3.3V \pm 5\%$ or $2.5V \pm 5\%$ , $T_{A} = 0^{\circ}\text{C}$ to $70^{\circ}\text{C}$

Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
V <sub>IH</sub>	Input High Voltage	SEL		2		V <sub>DD</sub> + 0.3	V
V <sub>IL</sub>	Input Low Voltage	SEL		-0.3		0.8	V
I <sub>IH</sub>	Input High Current	SEL	$V_{DD} = V_{IN} = 3.465V$			5	μΑ
I	Input Low Current	SEL	$V_{DD} = 3.465V, V_{IN} = 0V$	-150			μΑ
V	Output High Voltage; NOTE 1		$V_{DDO} = 3.3V \pm 5\%$	2.6			V
V <sub>OH</sub>			$V_{DDO} = 2.5V \pm 5\%$	1.8			V
V <sub>OL</sub>	Output Low Voltage; NOTE 1		$V_{DDO} = 3.3V \text{ or } 2.5V \pm 5\%$			0.5	V

NOTE 1: Outputs terminated with  $50\Omega$  to  $V_{DDO}/2$ . See Parameter Measurement Information, Output Load Test Circuit.

#### TABLE 4. CRYSTAL CHARACTERISTICS

Parameter	Test Conditions	Minimum	Typical	Maximum	Units
Mode of Oscillation		Fundamental			
Frequency			26.5625		MHz
Equivalent Series Resistance (ESR)				50	Ω
Shunt Capacitance				7	pF
Drive Level				1	mW

NOTE: Characterized using an 18pF parallel resonant crystal.



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Table 5A. AC Characteristics,  $V_{DD} = V_{DDO} = 3.3V \pm 5\%$ , Ta = 0°C to 70°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
				212.5		MHz
f <sub>out</sub>	Output Frequency Range			106.25		
				75		
tsk(o)	Output Skew; NOTE 1, 3			TBD		ps
	RMS Phase Jitter (Random); NOTE 2	212.5MHz @ Integration Range: 2.55MHz - 20MHz		0.50		ps
<i>t</i> jit(Ø)		106.25MHz @ Integration Range: 637kHz - 5MHz		0.86		ps
		75MHz @ Integration Range: 12kHz - 20MHz		TBD		ps
t <sub>R</sub> / t <sub>F</sub>	Output Rise/Fall Time	20% to 80%		400		ps
odc	Output Duty Cycle			50		%

NOTE 1: Defined as skew between outputs at the same supply voltages and with equal load conditions.

Measured at V<sub>DDO</sub>/2.

NOTE 2: Please refer to the Phase Noise Plot.

NOTE 3: This parameter is defined in accordance with JEDEC Standard 65.

Table 5B. AC Characteristics,  $V_{DD} = 3.3V \pm 5\%$ ,  $V_{DDO} = 2.5V \pm 5\%$ , Ta = 0°C to 70°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
				212.5		MHz
f <sub>out</sub>	Output Frequency Range			106.25		
				75		
tsk(o)	Output Skew; NOTE 1, 3			TBD		ps
	RMS Phase Jitter (Random); NOTE 2	212.5MHz @ Integration Range: 2.55MHz - 20MHz		0.57		ps
T(1)T(1/2)		106.25MHz @ Integration Range: 637kHz - 5MHz		1.1		ps
		75MHz @ Integration Range: 12kHz - 20MHz		TBD		ps
t <sub>R</sub> / t <sub>F</sub>	Output Rise/Fall Time	20% to 80%		450		ps
odc	Output Duty Cycle			50		%

NOTE 1: Defined as skew between outputs at the same supply voltages and with equal load conditions.

Measured at  $V_{DDO}/2$ .

NOTE 2: Please refer to the Phase Noise Plot.

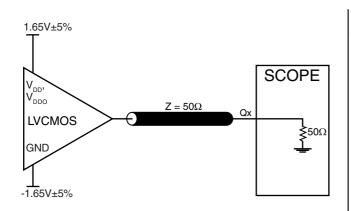
NOTE 3: This parameter is defined in accordance with JEDEC Standard 65.

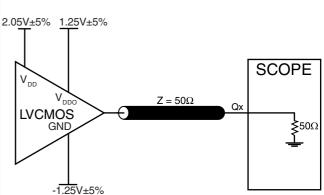


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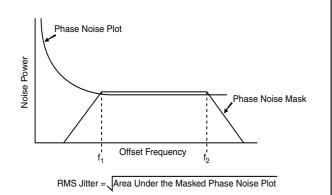
## PARAMETER MEASUREMENT INFORMATION

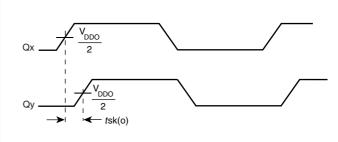




#### 3.3V CORE/3.3V OUTPUT LOAD AC TEST CIRCUIT

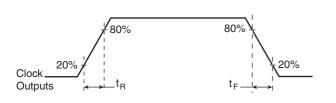
#### 3.3V CORE/2.5V OUTPUT LOAD AC TEST CIRCUIT

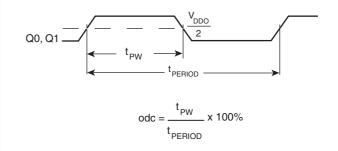




#### RMS PHASE JITTER

## OUTPUT SKEW





#### OUTPUT RISE/FALL TIME

OUTPUT DUTY CYCLE/PULSE WIDTH/PERIOD



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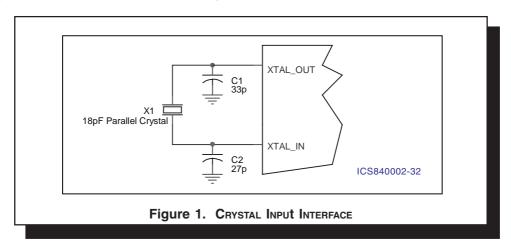
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## **APPLICATION INFORMATION**

#### **CRYSTAL INPUT INTERFACE**

The ICS840002-32 has been characterized with 18pF parallel resonant crystals. The capacitor values shown in *Figure* 1

below were determined using an 18pF parallel resonant crystal and were chosen to minimize the ppm error.



## **RELIABILITY INFORMATION**

### Table 6. $\theta_{\text{JA}}$ vs. Air Flow Table for 8 Lead TSSOP

θ<sub>JA</sub> by Velocity (Meters Per Second)

0 1 2.5

Multi-Layer PCB, JEDEC Standard Test Boards 101.7°C/W 90.5°C/W 89.8°C/W

#### TRANSISTOR COUNT

The transistor count for ICS840002-32 is: 2322



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#### PACKAGE OUTLINE - G SUFFIX FOR 8 LEAD TSSOP

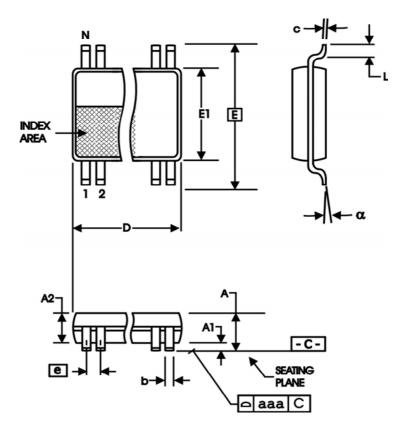


TABLE 7. PACKAGE DIMENSIONS

SYMBOL	Millin	neters			
STWIBOL	Minimum	Maximum			
N	8				
A		1.20			
A1	0.05	0.15			
A2	0.80	1.05			
b	0.19	0.30			
С	0.09	0.20			
D	2.90	3.10			
E	6.40 E	BASIC			
E1	4.30	4.50			
е	0.65 E	BASIC			
L	0.45	0.75			
α	0°	8°			
aaa		0.10			

Reference Document: JEDEC Publication 95, MO-153



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#### TABLE 8. ORDERING INFORMATION

Part/Order Number	Marking	Package	Shipping Packaging	Temperature
ICS840002BG-32	02B32	8 lead TSSOP	tube	0°C to 70°C
ICS840002BG-32T	02B32	8 lead TSSOP	2500 tape & reel	0°C to 70°C

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